UNISONIC TECHNOLOGIES CO., LTD

SB540 DIODE

5.0A SCHOTTKY BARRIER RECTIFIER

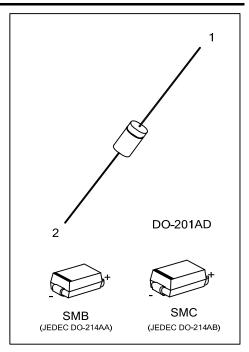
DESCRIPTION

The UTC SB540 is 5.0A schottky barrier rectifier. it uses UTC's advanced technology to provide customers with high current capability and low forward voltage drop, etc.

The UTC SB540 is suitable for free wheeling, low voltage and polarity protection applications, etc.

FEATURES

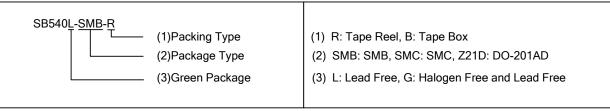
- * Metal to silicon rectifier, majority carrier conduction.
- * For use in low voltage, high frequency inverters free wheeling, and polarity protection applications.
- * Low power loss, high efficiency.
- * High current capability, low V_F.
- * High surge capacity.



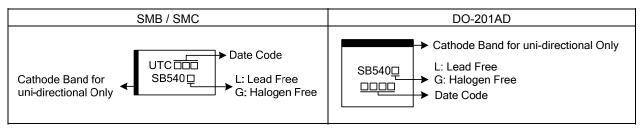
ORDERING INFORMATION

Ordering Number		Daakaga	Pin Assignment		Dooking	
Lead Free	Halogen Free	Package	1	2	Packing	
SB540L-SMB-R	SB540G-SMB-R	SMB	K	Α	Tape Reel	
SB540L-SMC-R	SB540G-SMC-R	SMC	K	Α	Tape Reel	
SB540L-Z21D-B	SB540G-Z21D-B	DO-201AD	K	Α	Tape Box	

K: Cathode Note: Pin Assignment: A: Anode



MARKING



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■ ABSOLUTE MAXIMUM RATINGS (T_A =25°C unless otherwise specified.)(Note 2)

PARAMETER		SYMBOL	RATINGS	UNIT	
DC Blocking Voltage		V_R	40	V	
Peak Repetitive Reverse Voltage		V_{RRM}	40	>	
Working Peak Reverse Voltage		V_{RWM}	40	>	
RMS Reverse Voltage		$V_{R(RMS)}$	28	>	
Average Rectified Output Current		Io	5.0	Α	
Non-repetitive Peak Forward Surge Current 8.3 ms Single Half-Sine-Wave		I _{FSM}	150	Α	
Power Dissipation	SMB/SMC	В	3.7	W	
	DO-201AD	P_D	5.0		
Junction Temperature		T_J	-65 ~ +150	ç	
Storage Temperature		T _{STG}	-65 ~ +150	°C	

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL DATA

PARAMETER		SYMBOL	RATINGS	UNIT	
Junction to Ambient (Note 2)	SMB/SMC	0	75	°C/A/	
Junction to Ambient (Note 3)	DO-201AD	θ _{JA}	40	°C/W	

■ **ELECTRICAL CHARACTERISTICS** (T_A =25°C unless otherwise specified.)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Reverse Breakdown Voltage (Note 1)	$V_{(BR)R}$	I _R =0.50mA	40			V
Forward Voltage Drop	VEM	I _F =5.0A, T _J =25°C			0.55	V
		I _F =5.0A, T _J =100°C			0.50	V
Leakage Current (Note 1)	DM	V _R =40V, T _J =25°C			0.50	mA
		V _R =40V, T _J =100°C			50	mA

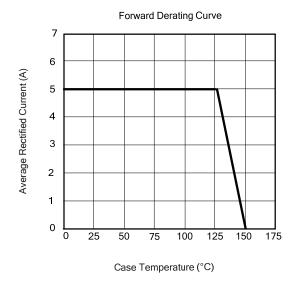
Notes: 1. Short duration pulse test used to minimize self-heating effect.

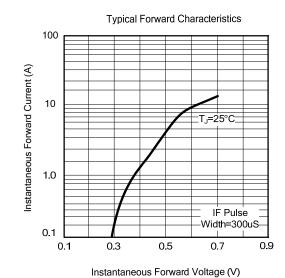
- 2. Thermal resistance junction to case mounted on heatsink.
- 3. 1 inch square pad size (1x0.5 inch for each lead) on FR4 board.

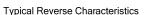
^{2.} These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

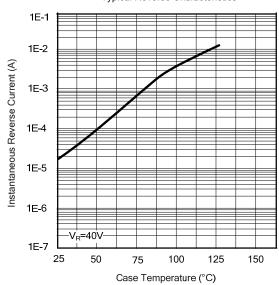
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■ TYPICAL CHARACTERISTICS









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